

LS5114 P-CHANNEL JFET



Linear Systems replaces discontinued Siliconix 2N5114

This analog switch is designed for inverting switching into inverting input of an Operational Amplifier.

The SOT-23 package provides ease of manufacturing, and a lower cost assembly option.

(See Packaging Information).

LS5114 Benefits:

- Low On Resistance
- $I_{D(off)} \le 500 \text{ pA}$
- Switches directly from TTL logic

LS5114 Applications:

- **Analog Switches**
- Commutators
- Choppers

| FEATURES | | | |
|--|---------------------------|--|--|
| | 1.4 | | |
| DIRECT REPLACEMENT FOR SILICONIX 2N511 | | | |
| LOW ON RESISTANCE | r _{DS(on)} ≤ 75Ω | | |
| LOW CAPACITANCE 6pF | | | |
| ABSOLUTE MAXIMUM RATINGS @ 25°C (un | less otherwise noted) | | |
| Maximum Temperatures | | | |
| Storage Temperature | -55°C to +200°C | | |
| Operating Junction Temperature | -55°C to +200°C | | |
| Maximum Power Dissipation | | | |
| Continuous Power Dissipation | 500mW | | |
| MAXIMUM CURRENT | | | |
| Gate Current (Note 1) | I _G = -50mA | | |
| MAXIMUM VOLTAGES | | | |
| Gate to Drain Voltage | V _{GDS} = 30V | | |
| Gate to Source Voltage | V _{css} = 30V | | |

ISEA 14 ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

| | TICAL CHARACTERISTICS @ 25 C (unless otherw | | | | | |
|----------------------|---|-----|------|------|-------|---|
| SYMBOL | CHARACTERISTIC | MIN | TYP. | MAX | UNITS | CONDITIONS |
| BV_{GSS} | Gate to Source Breakdown Voltage | 30 | | | - | $I_{G} = 1\mu A$, $V_{DS} = 0V$ |
| V _{GS(off)} | Gate to Source Cutoff Voltage | 4 | | 10 | | $V_{DS} = -15V, I_{D} = -1nA$ |
| V _{GS(F)} | Gate to Source Forward Voltage | | -0.7 | -1 | V | $I_G = -1 \text{mA}, V_{DS} = 0 \text{V}$ |
| • | Drain to Source On Voltage | | -1.0 | -1.3 | | $V_{GS} = 0V, I_{D} = -15mA$ |
| $V_{DS(on)}$ | | | -0.7 | | | $V_{GS} = 0V$, $I_D = -7mA$ |
| | | | -0.5 | | | $V_{GS} = 0V$, $I_D = -3mA$ |
| I _{DSS} | Drain to Source Saturation Current (Note 2) | -30 | | -90 | mA | $V_{DS} = -18V, V_{GS} = 0V$ |
| I _{GSS} | Gate Reverse Current | | 5 | 500 | | $V_{GS} = 20V, \ V_{DS} = 0V$ |
| I _G | Gate Operating Current | | -5 | | | $V_{DS} = -15V, I_{D} = -1mA$ |
| I _{D(off)} | Drain Cutoff Current | - | -10 | -500 | pΑ | $V_{DS} = -15V, V_{GS} = 12V$ |
| | | | -10 | | | $V_{DS} = -15V, V_{GS} = 7V$ |
| | | | -10 | - | | $V_{DS} = -15V, V_{GS} = 5V$ |
| r _{DS(on)} | Drain to Source On Resistance | | | 75 | Ω | $I_D = -1 \text{mA}, V_{GS} = 0 \text{V}$ |
| | | | | | | |

LS5114 DYNAMIC ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

| SYMBOL | CHARACTERISTIC | MIN | TYP. | MAX | UNITS | CONDITIONS |
|---------------------|-------------------------------|-----|------|-----|--------|--|
| g fs | Forward Transconductance | | 4.5 | | mS | $V_{DS} = -15V, I_D = 1mA, f = 1kHz$ |
| g os | Output Conductance | | 20 | | μS | |
| r _{DS(on)} | Drain to Source On Resistance | | | 75 | Ω | $I_D = 0A$, $V_{GS} = 0V$, $f = 1kHz$ |
| C _{iss} | Input Capacitance | | 20 | 25 | | $V_{DS} = -15V$, $V_{GS} = 0V$, $f = 1MHz$ |
| | | | 5 | 7 | pF | $V_{DS} = 0V$, $V_{GS} = 12V$, $f = 1MHz$ |
| C_{rss} | Reverse Transfer Capacitance | | 6 | | | $V_{DS} = 0V$, $V_{GS} = 7V$, $f = 1MHz$ |
| | | | 6 | | | $V_{DS} = 0V$, $V_{GS} = 5V$, $f = 1MHz$ |
| e _n | Equivalent Noise Voltage | | 20 | | nV/√Hz | $V_{DG} = 10V, I_D = 10mA, f = 1kHz$ |

LS5114 SWITCHING CHARACTERISTICS @ 25°C (unless otherwise noted)

| SYMBOL | CHARACTERISTIC | | UNITS | CONDITIONS |
|---------------------|--------------------|----|-------|----------------------------|
| t _{d(on)} | Turn On Time | 6 | | V _{GS} (L) = -11V |
| t _r | Turn On Rise Time | 10 | ns | $V_{GS}(H) = 0V$ |
| t _{d(off)} | Turn Off Time | 6 | 113 | See Switching Circuit |
| t _f | Turn Off Fall Time | 15 | | · · |

Note 1 - Absolute maximum ratings are limiting values above which LS5114 serviceability may be impaired. Note 2 - Pulse test: PW≤ 300 µs, Duty Cycle ≤ 3%

LS5114 SWITCHING CIRCUIT PARAMETERS

| V_{DD} | -10V |
|--------------------|-------|
| V_{GG} | 20V |
| R _L | 430Ω |
| R_{G} | 100Ω |
| I _{D(on)} | -15mA |

Micross Components Europe

Available Packages:

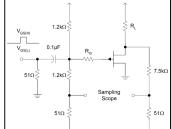
LS5114 in SOT-23 LS5114 in bare die.

Please contact Micross for full package and die dimensions

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SOT-23 (Top View)







Tel: +44 1603 788967

Email: chipcomponents@micross.com Web: http://www.micross.com/distribution